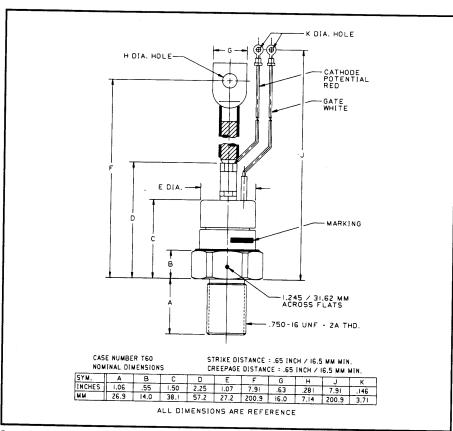


Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (412) 925-7272 Powerex, Europe, S.A. 428 Avenue G. Durand, BP107, 72003 Le Mans, France (43) 41.14.14

Phase Control SCR 150 Amperes Average 1600 Volts

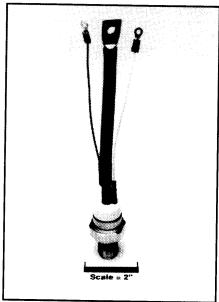


C180 (Outline Drawing)

Ordering Information:

Select the complete five or six digit part number you desire from the table, i.e. C180PM is a 1600 Volt, 150 Ampere Phase Control SCR.

	Voltage		Current	
Туре	V _{DRM} V _{RRM}	Code	l _{T(av)}	
C180	200	В	150	
	400	D		
	600	М		
	800	N		
	1000	Р	ĺ	
	1200	PB		
	1400	PD		
	1600	PM		



C180 Phase Control SCR 150 Amperes Average, 1600 Volts

Description:

Powerex Silicon Controlled Rectifiers (SCR) are designed for phase control applications. These are all-diffused, compression bonded encapsulated (CBE) devices employing the field-proven amplifying (di/namic) gate.

Features:

Low On-State Voltage
High di/dt
High dv/dt
Hermetic Packaging
Excellent Surge and I ² t Ratings

Applications:

Power Supplies
Battery Chargers

☐ Motor Control



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C180
Phase Control SCR
150 Amperes Average, 1600 Volts

Absolute Maximum Ratings

Appointe maximum reamigo			
	Symbol	C180	Units
DAG On State Current @ To - 90°C	I _{T(RMS)}	235	Amperes
RMS On-State Current @ T _C = 90°C		150	Amperes
Average On-State Current @ T _C = 90°C	I _{T(av)}	3500	Amperes
Peak One-Cycle Surge (Non Repetitive) On-State Current (60Hz)	TSM		
Peak One-Cycle Surge (Non-Repetitive) On-State Current (50Hz)	I _{TSM}	3200	Amperes
Peak One-Oycle Surge (North Topestry) Chan Ponetitivo)	di/dt	800	Amperes/μs
Critical Rate-of-Rise of On-State Current (Non-Repetitive)		150	Amperes/µs
Critical Rate-of-Rise of On-State Current (Repetitive)	di/dt		A ² sec
I²t (for Fusing), 8.3 milliseconds	l ² t	50,800	
Peak Gate Power Dissipation	P _{GM}	10	Watts
	P _{G(av)}	2	Watts
Average Gate Power Dissipation		-40 to 150	•c
Storage Temperature	T _{STG}		
	T,	_40 to 125	•C
Operating Temperature		250 to 300	inlb.
Mounting Torque		28 to 34	N-M
Mounting Torque		28 10 34	

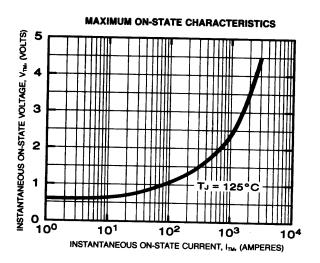
Electrical and Thermal Characteristics

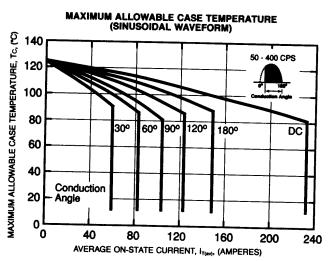
Cheracteristics	Symbol	Test Conditions	C180	Units
Voltage—Blocking State Maximums Forward Leakage, Peak	I _{DRM}	T _J = 125°C; V _{DRM} = Rated	20	mA
Reverse Leakage, Peak	I _{RRM}	T _J = 125°C; V _{RRM} = Rated	20	mA
Current—Conducting State Maximums Peak On-State Voltage	V _{TM}	$T_J = 25^{\circ}C, I_{TM} = 1500A$	2.85	Volts
Switching Typical Turn-Off Time	tq	$I_T=150A$, $T_J=125^{\circ}C$, $di_R/dt=12.5A/\mu sec$ Reapplied $dv/dt=20V/\mu sec$, Linear to $0.8V_{DRM}$, $V_R=50V$	100	μsec
Typical Delay Time	t _a	$I_T=100A,V_{DRM}=Rated$ Gate Supply = 10V Open Ckt, 25 Ω , 0.1 μ sec Rise Time	1.0	μsec
Min. Critical dv/dt exponential to V _{DRM}	dv/dt	T _J = 125°C, Gate Open	200	V/μsec
Thermal Maximum Thermal Resistance Junction to Case	R _{ex} c		0.14	*C/Watt
Case to Sink, Lubricated	R _{ecs}		0.075	C/ Wall
Gate — Maximum Parameters Gate Current to Trigger	I _{GT}	$T_C = 25^{\circ}C: V_D = 6Vdc, R_L = 3\Omega$	150	mA_
Gate Voltage to Trigger	V _{GT}	$T_{C}=-40^{\circ}C$ to 125°C, $V_{D}=6Vdc$, $R_{L}=3\Omega$	3.0	Volts Volts
Non-Triggering Gate Voltage	V _{GDM}	$T_J=125^{\circ}\text{C}$, Rated V_{DRM} , $R_L=1000\Omega$	0.15	
Peak Forward Gate Current	I _{GTM}		10	Amperes Volts
Peak Reverse Gate Voltage	V_{GRM}		5	VOILS

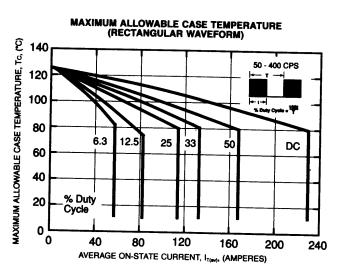


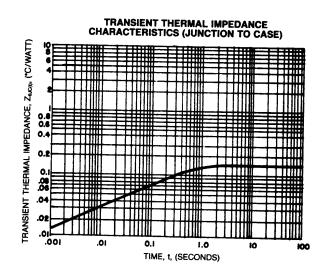
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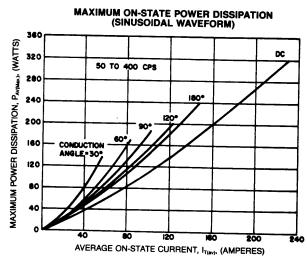
C180
Phase Control SCR
150 Amperes Average, 1600 Volts

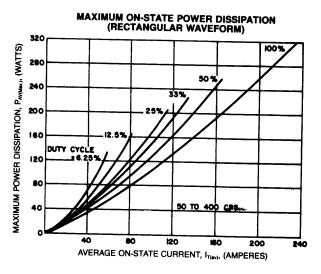








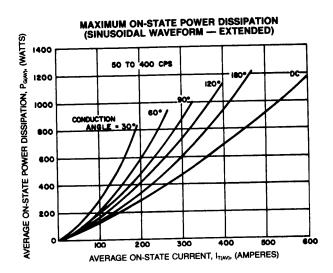


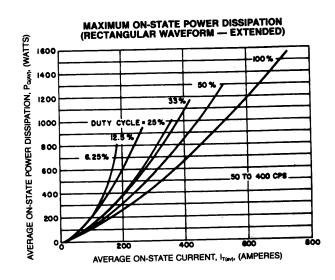


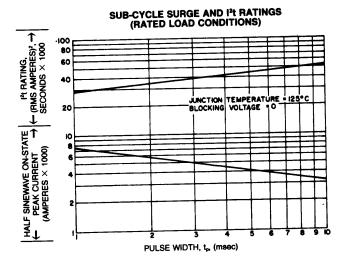


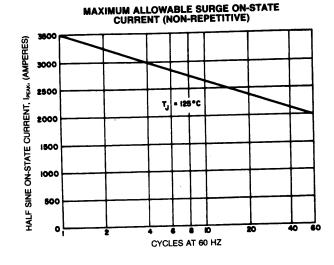
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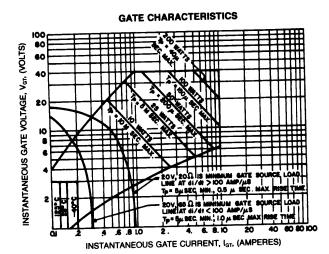
Phase Control SCR 150 Amperes Average, 1600 Volts











- Maximum allowable average gate dissipation = 5 watts.
- 2. The locus of possible dc trigger points lie outside the boundaries shown at various case
- 3. Tp = Rectangular gate current pulse width (5 μ s min. duration; 1.0 μ s max. rise time for 20V, 65 Ω source).
- 4. 20V, 0011 source). 4. $20V-20\Omega$ is the minimum gate source load line when rate of circuit current rise > 100 Amps/ μ s or anode rate of current rise > 200 Amps/ μ s ($t_p=5\mu$ s min., 0.5μ s max. rise

Maximum long-term repetitive anode di/dt =500 Amps/ μs with 20V -20Ω gate source.